

brazed-lead assembly to Patent No. 3,930,306

## Vishay General Semiconductor

## **Glass Passivated Ultrafast Rectifier**



PRIMARY CHARACTERISTICS			
I <sub>F(AV)</sub>	1.0 A		
V <sub>RRM</sub>	600 V		
I <sub>FSM</sub>	30 A		
t <sub>rr</sub>	30 ns		
V <sub>F</sub>	1.3 V		
T <sub>J</sub> max.	175 °C		

#### **FEATURES**





· Ideal for printed circuit boards

· Ultrafast reverse recovery time

Low forward voltage drop

Low leakage current

· Low switching losses, high efficiency

High forward surge capability

Meets environmental standard MIL-S-19500

Solder dip 260 °C, 40 s

 Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### **TYPICAL APPLICATIONS**

For use in high frequency rectification freewheeling application in switching mode converters inverters for consumer, computer telecommunication.

#### **MECHANICAL DATA**

Case: DO-204AL, molded plastic over glass body

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL	VALUE	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	600	V
Maximum RMS voltage	$V_{RMS}$	420	V
Maximum DC blocking voltage	$V_{DC}$	600	V
Maximum average forward rectified current 0.375" (9.5 mm) lead length at $T_L = 85$ °C (Fig. 1)	I <sub>F(AV)</sub>	1.0	Α
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30	А
Non repetitive peak reverse energy (1)	E <sub>RSM</sub>	5.0	mJ
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 175	°C

#### Note:

(1) Peak reverse energy measured with  $8/20~\mu s$  surge

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT
Minimum avalanche breakdown voltage	100 μΑ		V <sub>BR</sub>	600	V
Maximum instantaneous forward voltage	1.0 A	T <sub>J</sub> = 25 °C T <sub>J</sub> = 175 °C	V <sub>F</sub>	2.5 1.3	V
Maximum DC reverse current at rated DC blocking voltage		T <sub>A</sub> = 25 °C T <sub>A</sub> = 165 °C	I <sub>R</sub>	5.0 150	μΑ
Max. reverse recovery time	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1.0 A, I <sub>rr</sub> = 0.25 A		t <sub>rr</sub>	30	ns
Maximum junction capacitance	4.0 V, 1 MHz		CJ	45	pF
Maximum reverse recovery current slope	$I_F = 1 \text{ A}, V_R = 30 \text{ V}, di_f/dt = -1 \text{ A}/\mu\text{s}$		dl <sub>r</sub> /dt	7.0	A/μs

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL VALUE UNIT		
Typical thermal resistance (1)(2)	$egin{array}{l} R_{ hetaJA} \ R_{ hetaJL} \end{array}$	70 16	°C/W

#### Notes:

- (1) Thermal resistance from junction to ambient at 0.375" (9.5 mm) lead length, mounted on P.C.B. with 0.5 x 0.5" (12 x 12 mm) copper pads
- (2) Thermal resistance from junction to lead at 0.375" (9.5 mm) lead length with both leads attached to heatsink

ORDERING INFORMATION (Example)					
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
SBYV26C-E3/54	0.339	54	5500	13" diameter paper tape and reel	
SBYV26C-E3/73	0.339	73	3000	Ammo pack packaging	
SBYV26CHE3/54 (1)	0.339	54	5500	13" diameter paper tape and reel	
SBYV26CHE3/73 (1)	0.339	73	3000	Ammo pack packaging	

#### Note:

(1) Automotive grade AEC Q101 qualified

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

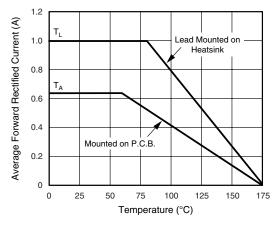


Figure 1. Maximum Forward Current Derating Curve

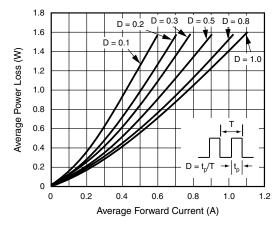


Figure 2. Forward Power Loss Characteristics



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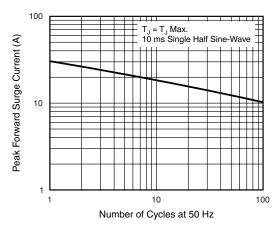


Figure 3. Maximum Non-Repetitive Peak Forward Surge Current

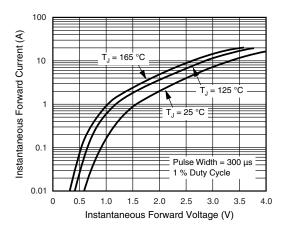


Figure 4. Typical Instantaneous Forward Characteristics

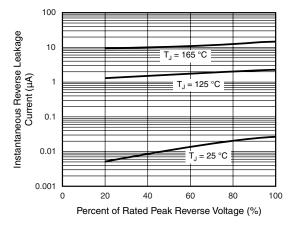


Figure 5. Typical Reverse Leakage Characteristics

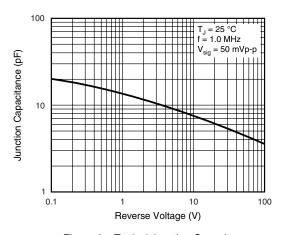


Figure 6. Typical Junction Capacitance

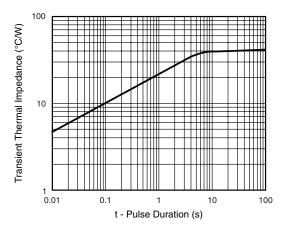


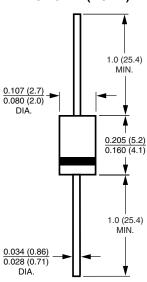
Figure 7. Typical Transient Thermal Impedance

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### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

### DO-204AL (DO-41)





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